



100V NPN ULTRA-LOW VCE(sat) TRANSISTOR IN PowerDI3333-8

Features

- BVcEo > 100V
- BVEBO > 8V
- Continuous Current Ic to 4A
- Peak Pulse Current Icm to 8A
- Ultra-Low Saturation Voltage VcE(sat) < 60mV @ 1A
- High Current RcE(sat) = 32mΩ Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Rated to +175°C Ideal for High-Temperature Environments
- Complementary PNP Type: <u>DXTP78100CFGQ</u>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTN78100CFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

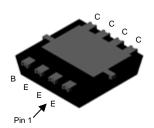
Applications

- MOSFET & IGBT gate drivers
- Load switches
- Low-voltage regulation
- DC to DC converters
- Motor, solenoid, relay and actuator drivers control

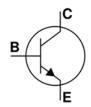
PowerDI3333-8/SWP (Type UX)



Top View



Bottom View



Device Symbol

Ordering Information (Note 4)

Orderable Part Number	derable Part Number Package Marking Reel Size (inc		Reel Size (inches)	es) Tape Width (mm)	Packing	
Orderable Fait Number	Fackage	Warking	Reel Size (Iliches)	rape widin (ililii)	Qty.	Carrier
DXTN78100CFGQ-7	PowerDI3333-8/SWP (Type UX)	2Y1	7	12	2,000	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI3333-8/SWP (Type UX)



2Y1 = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 25 = 2025)

WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	150	V
Collector-Emitter Voltage	VCEO	100	V
Emitter-Base Voltage	V _{EBO}	8	V
Continuous Collector Current (Note 5)	Ic	2	Α
Continuous Collector Current (Note 7)	Ic	4	Α
Peak Pulse Current	Ісм	8	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		900	mW
Power Dissipation	(Note 6)	PD	1.6	W
	(Note 7)		2.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	92	°C/W
	(Note 7)		62.5	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	8	°C/W
Thermal Resistance, Junction to Lead (Note 8)		Røjl	6.5	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	IV

Notes: 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.

- 6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 8. Thermal resistance from junction to solder-point (at the collector tab).
- 9. Refer to JEDEC specification JESD22-A114, JESD22-A115 and JESD22-C101.



Thermal Characteristics and Derating Information

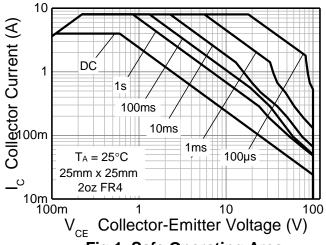


Fig 1. Safe Operating Area

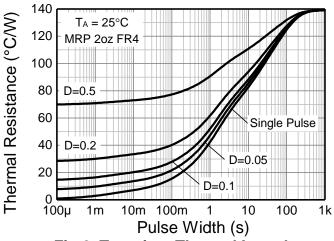


Fig 2. Transient Thermal Impedance

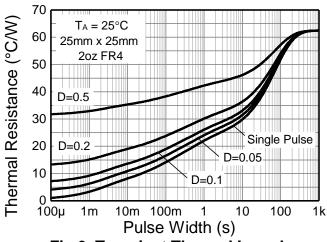


Fig 3. Transient Thermal Impedance

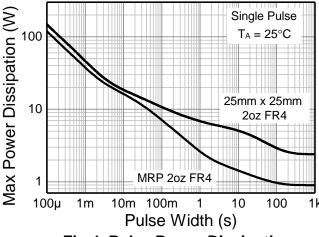


Fig 4. Pulse Power Dissipation

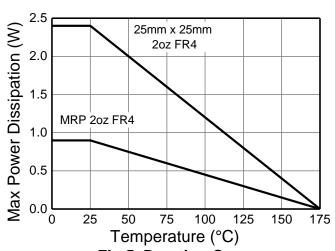


Fig 5. Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	150	_	_	V	Ic = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BVceo	100	_	_	V	Ic = 10mA
Emitter-Collector Breakdown Voltage	BV _{ECO}	5	_	_	V	I _E = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	8	_	_	V	I _E = 100μA
Collector Cut-off Current	Ісво	_	_	100	nA	V _{CB} = 150V
Collector Cut-on Current		_	_	10	μA	V _{CB} = 150V, T _A = +125°C
Collector Cut-off Current	I _{CES}	_		300	nA	V _{CE} = 80V
Emitter Cut-off Current	IEBO	_	_	50	nA	V _{EB} = 7V
		_	80	_	mV	Ic = 100mA, I _B = 1mA
		_	100	150	mV	I _C = 1A, I _B = 20mA
Collector-Emitter Saturation Voltage (Note 10)	VCE(sat)	_	40	60	mV	Ic = 1A, I _B = 100mA
		_	70	120	mV	Ic = 2A, I _B = 200mA
		_	130	340	mV	Ic = 4A, I _B = 400mA
Door Emitter Seturation Voltage (Note 10)	V _{BE} (sat)	_	870	1,000	mV	Ic = 2A, I _B = 200mA
Base-Emitter Saturation Voltage (Note 10)		_	950	1,100	mV	Ic = 4A, I _B = 400mA
Dago Emittor Turn On Voltage (Note 10)	V _{BE(on)}	_	770	850	mV	Ic = 2A, VcE = 2V
Base-Emitter Turn-On Voltage (Note 10)		_	850	950	mV	I _C = 4A, V _{CE} = 2V
	h _{FE}	200	320	_		Ic = 10mA, VcE = 2V
		250	320	420		Ic = 100mA, VcE = 2V
DC Comment Coin (Note 10)		210	300	_	_	I _C = 500mA, V _{CE} = 2V
DC Current Gain (Note 10)		140	200	_		Ic = 1A, VcE = 2V
		35	80	_		Ic = 2A, VcE = 2V
		10	30	_		Ic = 4A, VcE = 2V
Input Capacitance	C _{ibo}	_	360	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	Cobo	_	12.5	_	pF	V _{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	fτ	150	210	_	MHz	V _{CE} = 10V, I _C = 100mA, f = 50MHz
Turn-On Time	t _d		12.5	_	ns	
	tr	_	145	_	ns	Vcc = 10V, Ic = 2A,
Turn-Off Time	ts	_	430	_	ns	$I_{B1} = -I_{B2} = 200 \text{mA}$
	tf		83		ns	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

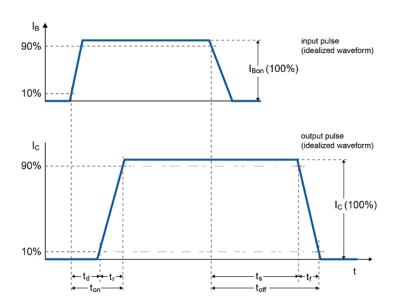


Fig 6. Timing Waveform



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

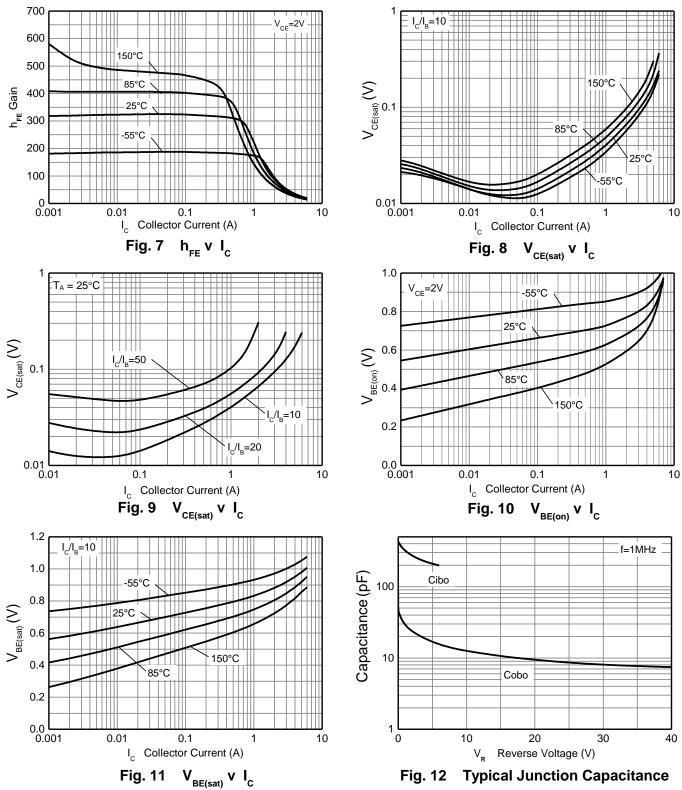


Fig. 12 **Typical Junction Capacitance**



Typical Electrical Characteristics (continued) (@TA = +25°C, unless otherwise specified.)

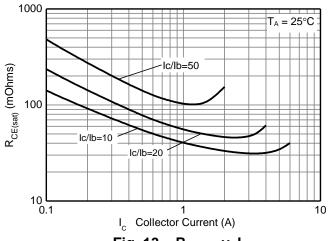


Fig. 13 $R_{CE(sat)} v I_{C}$

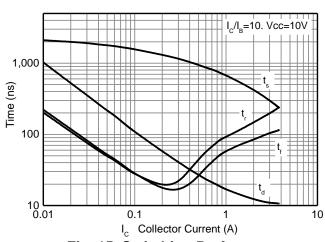


Fig. 15 Switching Performance

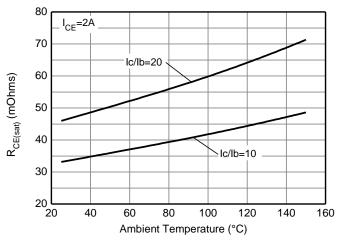


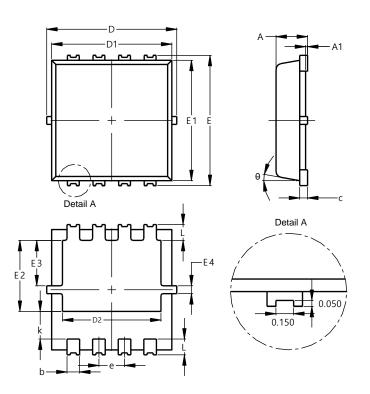
Fig. 14 $R_{CE(sat)} v T_A$



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8/SWP (Type UX)

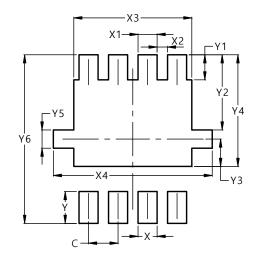


PowerDI3333-8/SWP						
	(Type UX)					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
С	0.650
Χ	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Notes:

- 11. For high-voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.12. Side wall tin plated package for wettable flanks in AOI.



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